

Appln. No. 10/721,086

Atty. Docket No. T3844-8802US01
XA-9985

Amendments to the Claims:

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This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

1. (Currently Amended) A storage device comprising one or more semiconductor memories and an information processing section which performs a first operation for reading reads data stored in the one or more semiconductor memories and a second operation for writing data to the one or more semiconductor memories based on an operating program and instructs a predetermined process and an operation to write data in accordance with commands received from outside thereof,

wherein the information processing section detects an error state associated with an area in the semiconductor memory,

substitutes the area during an idle state causing no operations in the storage device, where operations are not being performed in response to the commands, when the area is assumed error state is indicated to be a critical state, and

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substitutes the area immediately when the ~~area is~~
assumed error state is indicated to be a limit state.

2. (Currently Amended) The storage device
according to claim 1,

wherein a factor for the information processing
section to determine a critical state as the error state
comprises one or more of an insufficiency of a substitute
free area, a successive retry error, a time over of an
erasure time or a program time, an erasure count, an over
current of performing a read operation or a write operation,
and a ~~less~~-low current value of externally supplied power;
and

wherein a factor for the information processing
section to determine a limit state as the error state
comprises one or more of an insufficiency of a substitute
free area, a successive retry error, an ECC uncorrectable
error at retention failure, a device code unreadable error,
a time over of an erasure time or a program time, an erasure
count, an over current of performing a read operation or a
write operation, and a ~~less~~-low current value of externally
supplied power.

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3. (Original) The storage device according to claim 2 capable of independently setting the factors for the information processing section to determine a critical state and setting the factors for the information processing section to determine a limit state.

4. (Original) The storage device according to claim 3,

wherein a substitution destination area substituted by the information processing section is a free area in the semiconductor memory or semiconductor memory for substitution only.

5. (Original) The storage device according to claim 4,

wherein, when the substitution destination area is a free area in the semiconductor memory, the substitution destination area is a physical area controlled by an individual peripheral circuit which controls any of a plurality of sectors provided for a memory mat.

6. (Original) The storage device according to claim 5, wherein a decode method of the device substitutes only data in a substitution origin area for data in a

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substitution destination area, after substitution, allows access to the substitution destination area instead of the substituted area, and allows access to an unsubstituted area in the same manner as before the substitution.

7. (Currently Amended) The storage device according to claim 1,

wherein the information processing section notifies an outside of an emergency condition when determining that the area the error state is in a indicated to be the limit state.

8. (Currently Amended) The storage device according to claim 7, wherein one or more restricting operations, such as including inhibiting a write operation, are performed in the limit state.

9. (Original) The storage device according to claim 8,

wherein the information processing section copies data from a substitution origin area to a substitution destination area during the area substitution and corrects a correctable error if it is contained in the data.

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10. (Currently Amended) The storage device
according to claim 9, further comprising:
a detection circuit for detecting an area state;
a notification circuit for notifying an outside of
a detection result and an area substitution state;
an area substitution circuit for performing area
substitution; and
an area decode management circuit for managing
permission or inhibition of access to areas.